

SN5413, SN54LS13, SN7413, SN74LS13
**DUAL 4-INPUT
 POSITIVE-NAND SCHMITT TRIGGERS**
 DECEMBER 1983—REVISED MARCH 1988

SDLS046

- Operation from Very Slow Edges
- Improved Line-Receiving Characteristics
- High Noise Immunity

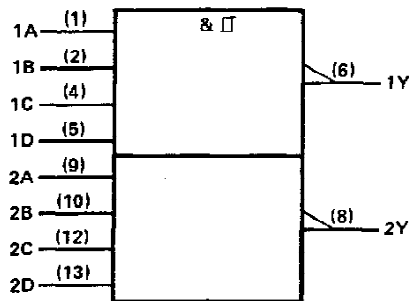
description

Each circuit functions as a 4-input NAND gate, but because of the Schmitt action, it has different input threshold levels for positive (V_{T+}) and for negative going (V_{T-}) signals.

These circuits are temperature-compensated and can be triggered from the slowest of input ramps and still give clean, jitter-free output signals.

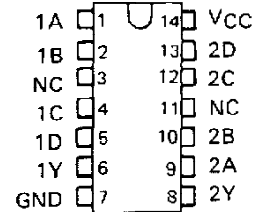
The SN5413 and SN54LS13 are characterized for operation over the full military temperature range of -55°C to 125°C . The SN7413 and SN74LS13 are characterized for operation from 0°C to 70°C .

logic symbol†

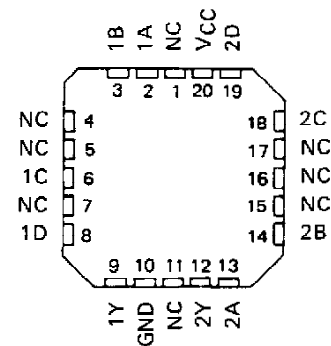


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-13. Pin numbers shown are for D, J, N, and W packages.

SN5413, SN54LS13 . . . J OR W PACKAGE
 SN7413 . . . N PACKAGE
 SN74LS13 . . . D OR N PACKAGE
 (TOP VIEW)

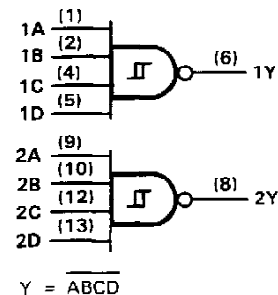


SN54LS13 . . . FK PACKAGE
 (TOP VIEW)



NC—No internal connection

logic diagram (positive logic)



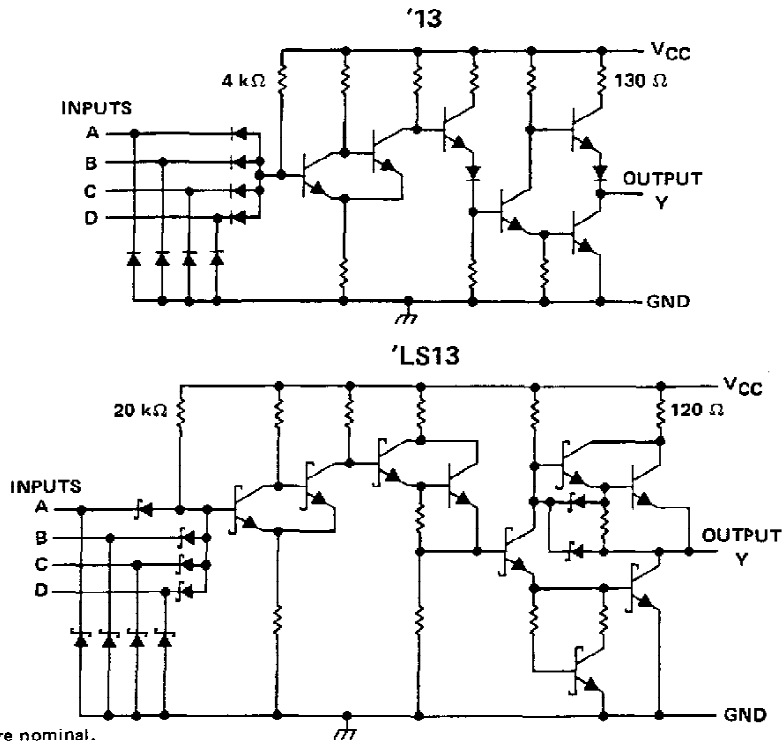
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SN5413, SN54LS13, SN7413, SN74LS13
DUAL 4-INPUT
POSITIVE-NAND SCHMITT TRIGGERS

schematics



Resistor values are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage: '13	5.5 V
'LS13	7 V
Operating free-air temperature: SN54'	-55°C to 125°C
SN74'	0°C to 70°C
Storage temperature range	-65°C to 150°C

NOTE 1: Voltage values are with respect to network ground terminal.



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SN5413, SN7413
DUAL 4-INPUT
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recommended operating conditions

	SN5413			SN7413			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
I _{OH} High-level output current			-0.8			-0.8	mA
I _{OL} Low-level output current			16			16	mA
T _A Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS [†]	MIN	TYP [‡]	MAX	UNIT
V _{T+}	V _{CC} = 5 V	1.5	1.7	2	V
V _{T-}	V _{CC} = 5 V	0.6	0.9	1.1	V
Hysteresis (V _{T+} - V _{T-})	V _{CC} = 5 V	0.4	0.8		V
V _{IK}	V _{CC} = MIN, I _I = -12 mA			-1.5	V
V _{OH}	V _{CC} = MIN, V _I = 0.6 V, I _{OH} = -0.8 mA	2.4	3.4		V
V _{OL}	V _{CC} = MIN, V _I = 2 V, I _{OL} = 16 mA		0.2	0.4	V
I _{T+}	V _{CC} = 5 V, V _I = V _{T+}		-0.65		mA
I _{T-}	V _{CC} = 5 V, V _I = V _{T-}		-0.85		mA
I _I	V _{CC} = MAX, V _I = 5.5 V			1	mA
I _{IH}	V _{CC} = MAX, V _{IH} = 2.4 V			40	μA
I _{IL}	V _{CC} = MAX, V _{IL} = 0.4 V		-1	-1.6	mA
I _{OS} §	V _{CC} = MAX,	-18		-55	mA
I _{CCH}	V _{CC} = MAX		14	23	mA
I _{CCL}	V _{CC} = MAX		20	32	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] All typical values are at V_{CC} = 5 V, T_A = 25° C.

§ Not more than one output should be shorted at a time.

switching characteristics, V_{CC} = 5 V, T_A = 25° C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 400 Ω, C _L = 15 pF		18	27	ns
t _{PHL}					15	22	ns


TEXAS
INSTRUMENTS

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SN54LS13, SN74LS13
DUAL 4-INPUT
POSITIVE-NAND SCHMITT TRIGGERS

recommended operating conditions

	SN54LS13			SN74LS13			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
I _{OH} High-level output current			-0.4			-0.4	mA
I _{OL} Low-level output current			4			8	mA
T _A Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	SN54LS13			SN74LS13			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{T+}	V _{CC} = 5 V	1.4	1.6	1.9	1.4	1.6	1.9	V
V _{T-}	V _{CC} = 5 V	0.5	0.8	1	0.5	0.8	1	V
Hysteresis (V _{T+} - V _{T-})	V _{CC} = 5 V	0.4	0.8		0.4	0.8		V
V _{IK}	V _{CC} = MIN, I _I = -18 mA			-1.5			-1.5	V
V _{OH}	V _{CC} = MIN, V _I = 0.5 V, I _{OH} = -0.4 mA	2.5	3.4		2.7	3.4		V
V _{OL}	V _{CC} = MIN, V _I = 1.9 V	I _{OL} = 4 mA		0.25	0.4	0.25		0.4
		I _{OL} = 8 mA				0.35	0.5	
I _{T+}	V _{CC} = 5 V, V _I = V _{T+}	-0.14			-0.14			mA
I _{T-}	V _{CC} = 5 V, V _I = V _{T-}	-0.18			-0.18			mA
I _I	V _{CC} = MAX, V _I = 7 V	0.1			0.1			mA
I _{IH}	V _{CC} = MAX, V _{IH} = 2.7 V	20			20			μA
I _{IL}	V _{CC} = MAX, V _{IL} = 0.4 V	-0.4			-0.4			mA
I _{OS} §	V _{CC} = MAX	-20		-100	-20		-100	mA
I _{CCH}	V _{CC} = MAX	2.9		6	2.9		6	mA
I _{CCL}	V _{CC} = MAX	4.1		7	4.1		7	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

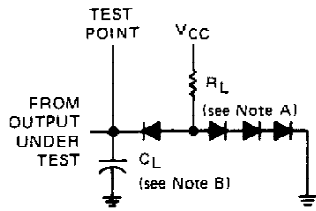
switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 2 kΩ,	C _L = 15 pF	15	22		ns
t _{PHL}					18	27		ns

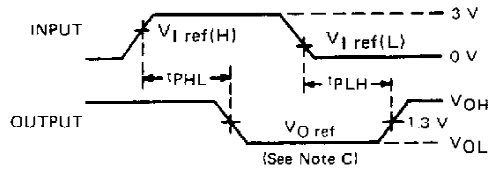


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PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT



VOLTAGE WAVEFORMS

NOTES: A. All diodes are 1N3064 or equivalent.
 B. C_L includes probe and jig capacitance.
 C. Generator characteristics and reference voltages are:

	Generator Characteristics				Reference Voltages		
	Z_{out}	PRR	t_r	t_f	$V_{I\ ref(H)}$	$V_{I\ ref(L)}$	$V_{O\ ref}$
SN54'/SN74'	50 Ω	1 MHz	10 ns	10 ns	1.7 V	0.9 V	1.5 V
SN54LS'/SN74LS'	50 Ω	1 MHz	15 ns	6 ns	1.6 V	0.8 V	1.3 V

TYPICAL CHARACTERISTICS OF '13 CIRCUITS

POSITIVE-GOING THRESHOLD VOLTAGE
 vs
 FREE-AIR TEMPERATURE

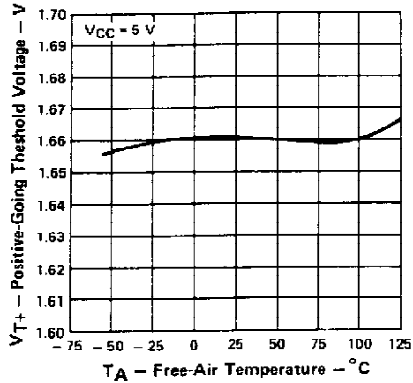


FIGURE 1

NEGATIVE-GOING THRESHOLD VOLTAGE
 vs
 FREE-AIR TEMPERATURE

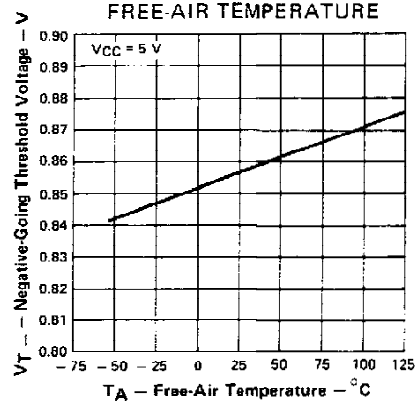


FIGURE 2

HYSTERESIS
 vs
 FREE-AIR TEMPERATURE

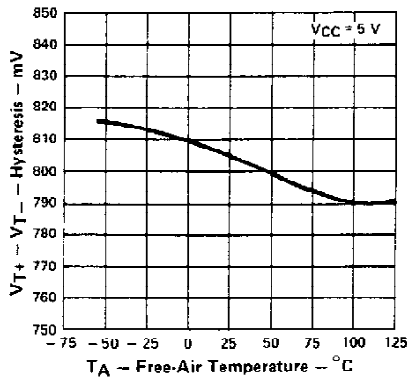
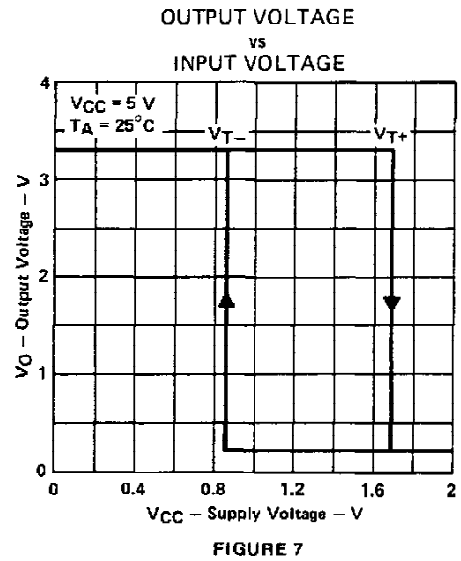
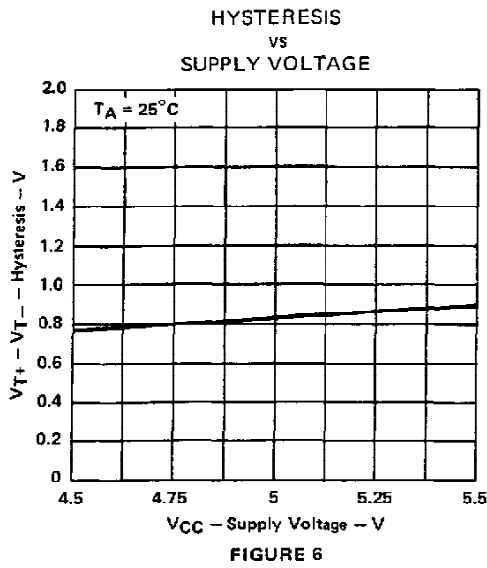
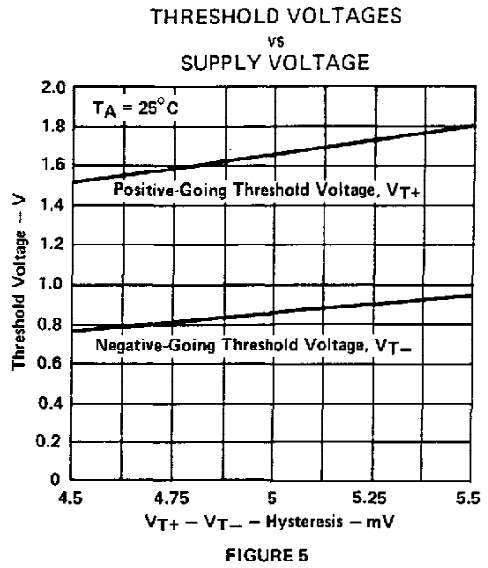
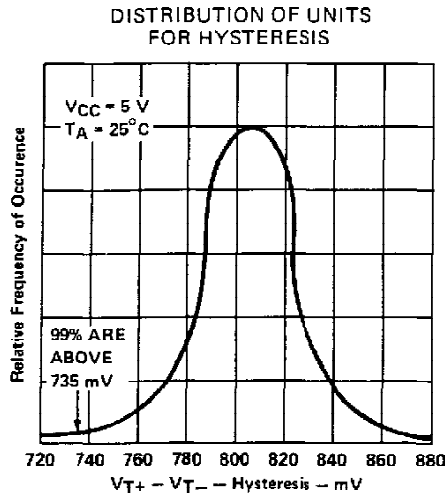


FIGURE 3

Data for temperatures below 0°C and 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN5413 only.

SN5413, SN7413
DUAL 4-INPUT
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TYPICAL CHARACTERISTICS OF '13 CIRCUITS



Data for temperatures below 0°C and 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN5413 only.

SN54LS13, SN74LS13
 DUAL 4-INPUT
 POSITIVE-NAND SCHMITT TRIGGERS

TYPICAL CHARACTERISTICS OF 'LS13 CIRCUITS

POSITIVE-GOING THRESHOLD VOLTAGE
 vs
 FREE-AIR TEMPERATURE

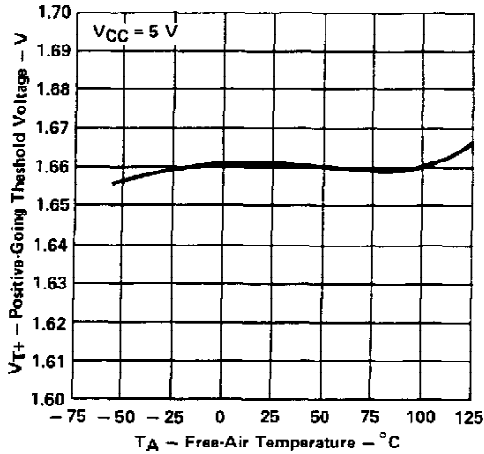


FIGURE 8

NEGATIVE GOING THRESHOLD VOLTAGE
 vs
 FREE-AIR TEMPERATURE

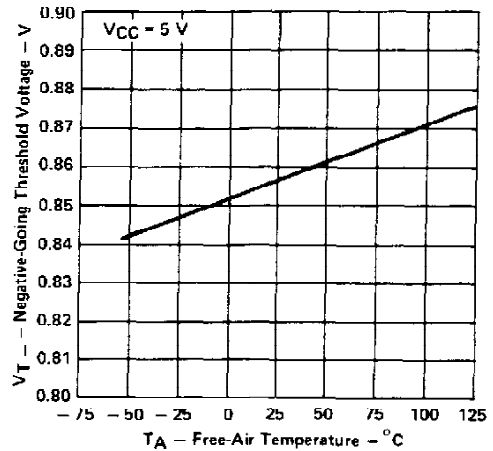


FIGURE 9

HYSTERESIS
 vs
 FREE-AIR TEMPERATURE

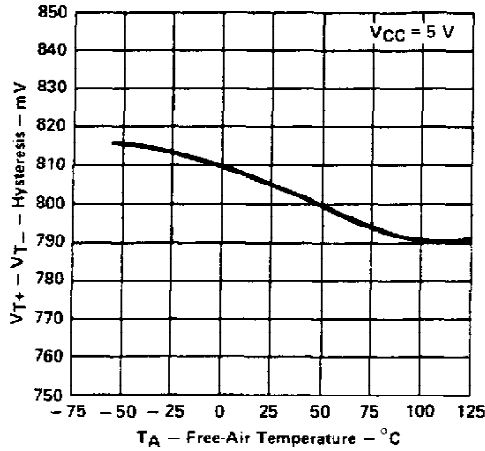


FIGURE 10

DISTRIBUTION OF UNITS
 FOR HYSTERESIS

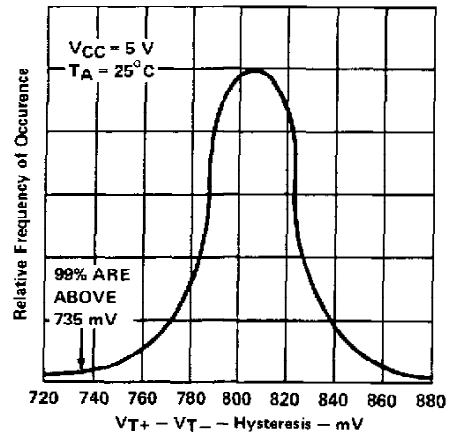


FIGURE 11

Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS13 only.

SN54LS13, SN74LS13
DUAL 4-INPUT
POSITIVE-NAND SCHMITT TRIGGERS

TYPICAL CHARACTERISTICS OF 'LS13 CIRCUITS

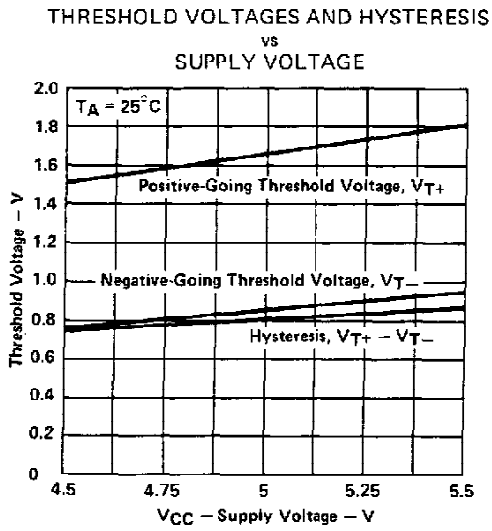


FIGURE 12

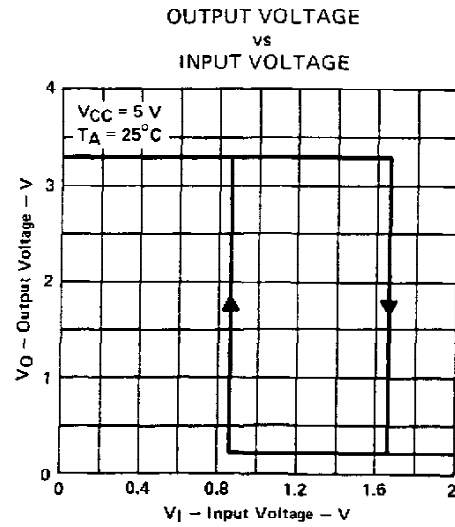
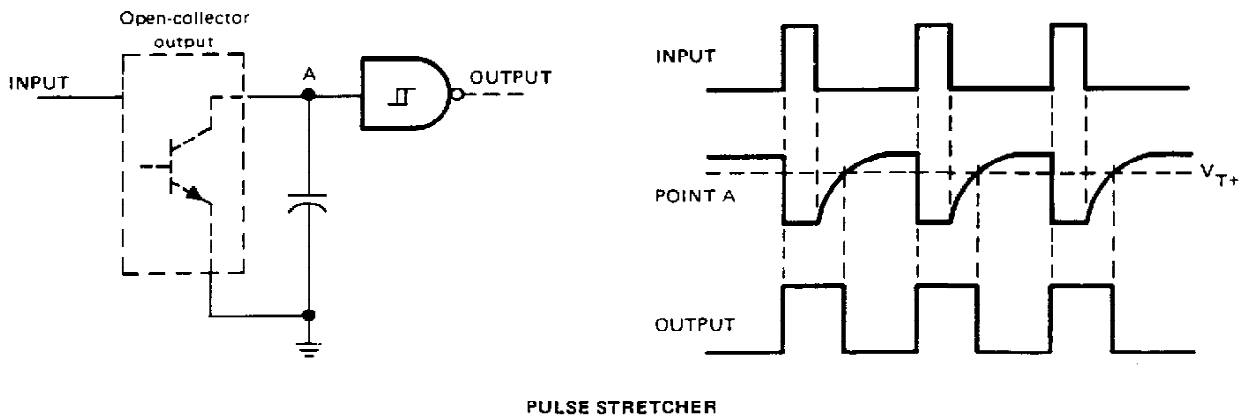
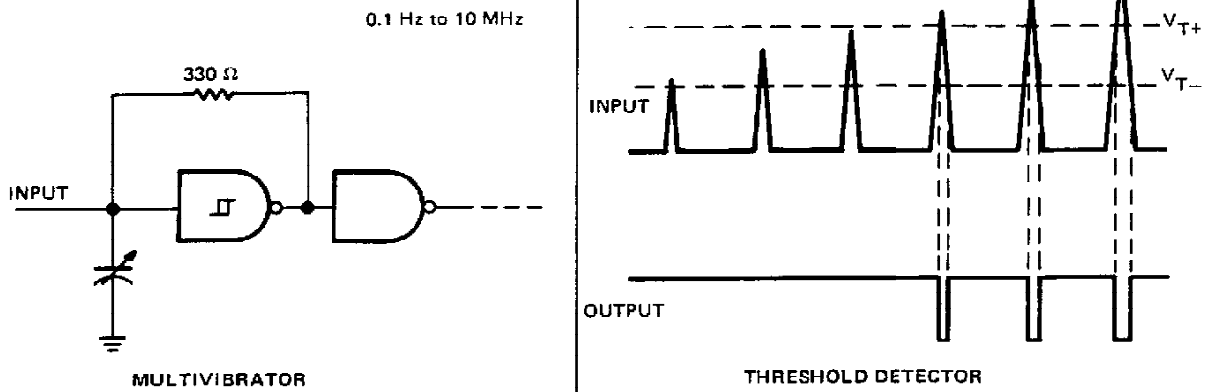
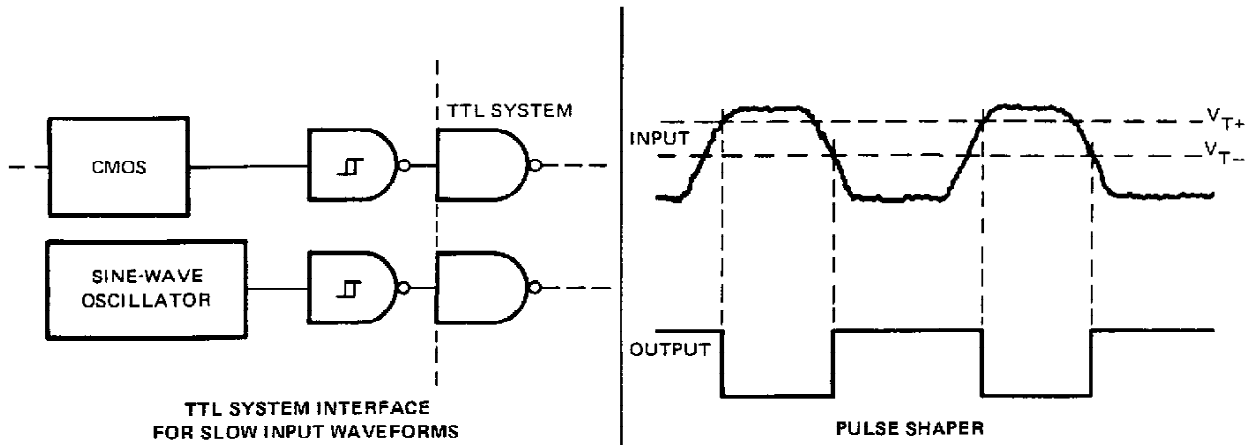


FIGURE 13

Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS13 only.

SN5413, SN54LS13, SN7413, SN74LS13
 DUAL 4-INPUT
 POSITIVE-NAND SCHMITT TRIGGERS

TYPICAL APPLICATION DATA



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